



# **ISC Silicon NPN Power Transistor**

### **DESCRIPTION**

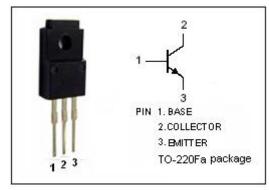
- · High Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 800V (Min)
- · High Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

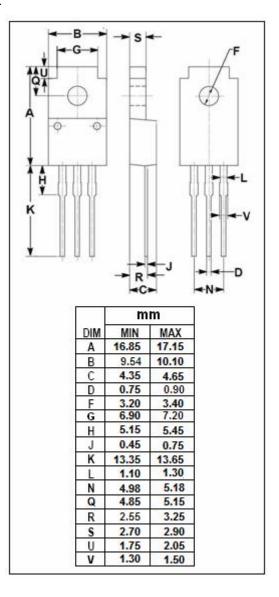
### **APPLICATIONS**

- · Switching regulator and high voltage switching applications.
- · High speed DC-DC converter applications.



SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	900	V	
Vceo	Collector-Emitter Voltage	800	V	
V <sub>EBO</sub>	Emitter-Base Voltage	7	V	
Ic	Collector Current-Continuous	3	A	
Ісм	Collector Current-Peak	5	А	
I <sub>B</sub>	Base Current-Continuous	1	А	
P <sub>C</sub>	Collector Power Dissipation @ T <sub>C</sub> =25℃	30	W	
	Collector Power Dissipation @ T <sub>a</sub> =25℃	2	VV	
Тл	Junction Temperature	150	$^{\circ}$ C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	







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2SC3559

#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA; I <sub>B</sub> = 0	800			V	
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA; I <sub>E</sub> = 0	900			V	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 0.8A; I <sub>B</sub> = 0.16A			0.6	V	
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 0.8A; I <sub>B</sub> = 0.16A			1.2	V	
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 800V; I <sub>E</sub> = 0			100	μА	
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 7V; I <sub>C</sub> = 0			1	mA	
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 0.8A; V <sub>CE</sub> = 5V	10				
Switching times							

tr	Rise Time			1.0	μS
t <sub>stg</sub>	Storage Time	$egin{array}{c} I_{B1} = 0.08A; I_{B2} = -0.2A \\ R_L = 500 Ω; V_{CC} \approx 400V \\ P_W = 20 μ s; Duty Cycle \leqslant 1% \\ \hline \end{array}$		4.0	μS
t <sub>f</sub>	Fall Time			1.0	μς

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